

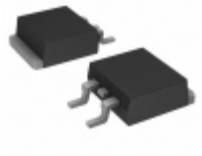







 	<h2 style="color: #E67E22;">FQB3N90TM</h2> <p>Hersteller-Teilenummer: FQB3N90TM</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 900V 3.6A D2PAK</p> <hr/> <p>Datenblätter:  FQB3N90TM.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 33902 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB3N90TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 900V 3.6A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	33902 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 130W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	900V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3.6A (Tc)
Rds On (Max) @ Id, Vgs	4.25 Ohm @ 1.8A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	26nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	910pF @ 25V
Verpackung	Tape & Reel (TR)







































FQB3N90TM ist neu im Original, Suche FQB3N90TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB3N90TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB3N90TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB3N80TM Fairchild/ON Semiconductor MOSFET N-CH 800V 3A D2PAK</p>	 <p>FQB3P20TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 2.8A D2PAK</p>	 <p>FQB3N60CTM Fairchild/ON Semiconductor MOSFET N-CH 600V 3A D2PAK</p>	 <p>FQB3N80 VB FQB3N80 VB</p>
 <p>FQB3N80TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 3A D2PAK</p>	 <p>FQB3P20TM Fairchild/ON Semiconductor MOSFET P-CH 200V 2.8A D2PAK</p>	 <p>FQB3N90TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 3.6A D2PAK</p>	 <p>FQB3P50TM Fairchild/ON Semiconductor MOSFET P-CH 500V 2.7A D2PAK</p>

heiße Teile

Mehr

 FQB33N10L	 FQB33N10LTM	 FQB33N10LTM	 FQB33N10TM	 FQB33N10TM
 FQB34N20	 FQB34N20L	 FQB34N20LTM	 FQB34N20LTM	 FQB34N20TM
 FQB34N20TM_AM002	 FQB34P10	 FQB34P10TM	 FQB34P10TM	 FQB34P10TM_F085
 FQB3N25TM	 FQB3N25TM	 FQB3N30TM	 FQB3N30TM	 FQB3N40TM
 FQB3N40TM	 FQB3N60C	 FQB3N80TM	 FQB3N80TM	 FQB3N90TM
 FQB3P20TM	 FQB3P20TM	 FQB3P50TM	 FQB3P50TM	 FQB44N10
 FQB44N10TM	 FQB44N10TM	 FQB46N15	 FQB46N15TM	 FQB47P06
 FQB47P06TM	 FQB4N20L	 FQB4N20LTM	 FQB4N20LTM	 FQB4N20TM
 FQB4N20TM	 FQB4N25TM	 FQB4N25TM	 FQB4N20TM	 FQB4N50TM
 FQB4N50TM	 FQB4N60C	 FQB4N80TM	 FQB4N80TM	 FQB4N90TM

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